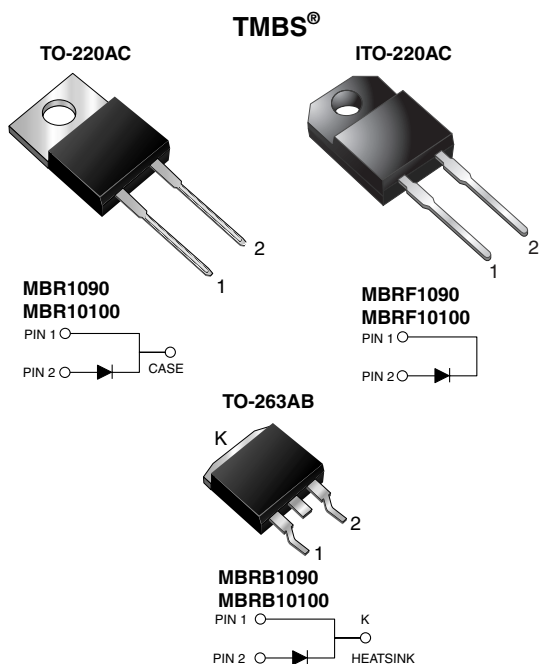




High-Voltage Schottky Rectifier



FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_{RRM}	90 V, 100 V
I_{FSM}	150 A
V_F	0.65 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current at $T_C = 133\text{ °C}$	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	150		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$, $L = 60\text{ mH}$	E_{AS}	130		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$, 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$	I_{RRM}	0.5		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μs
Isolation voltage (ITO-220AC only) From terminal to heatsink $t = 1\text{ min}$	V_{AC}	1500		V
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 150		°C

MBR(F,B)1090 & MBR(F,B)10100



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 10 A	T _C = 25 °C	V _F	0.80	V
	I _F = 10 A	T _C = 125 °C		0.65	
	I _F = 20 A	T _C = 125 °C		0.75	
Maximum reverse current at working peak reverse voltage ⁽²⁾		T _J = 25 °C T _J = 100 °C	I _R	100 6.0	μA mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	R _{θJA}	60	-	60	°C/W
	R _{θJC}	2.0	3.5	2.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

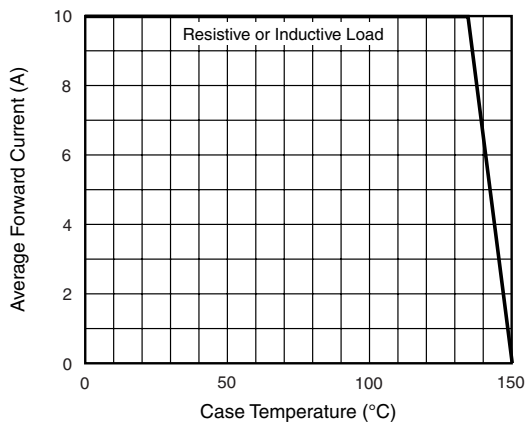


Figure 1. Forward Current Derating Curve

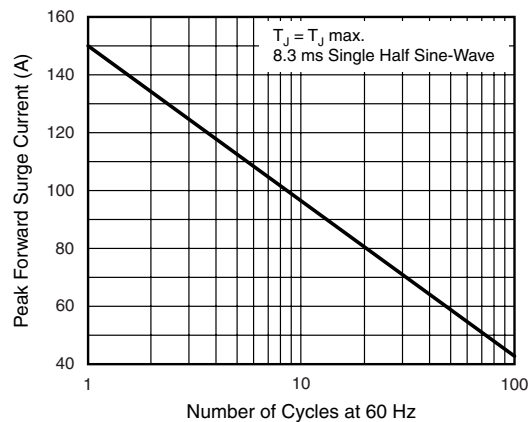


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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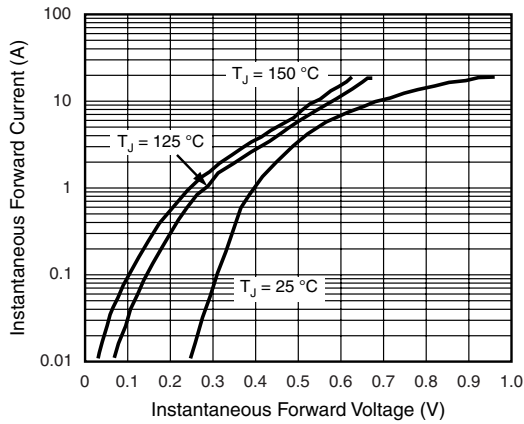


Figure 3. Typical Instantaneous Forward Characteristics

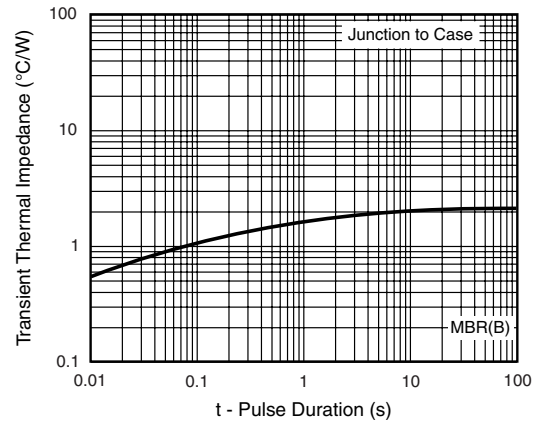


Figure 6. Typical Transient Thermal Impedance

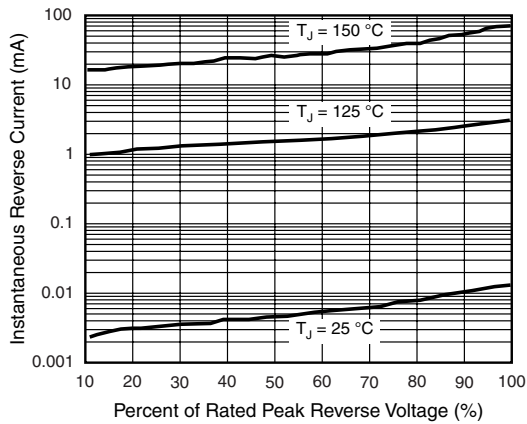


Figure 4. Typical Reverse Characteristics

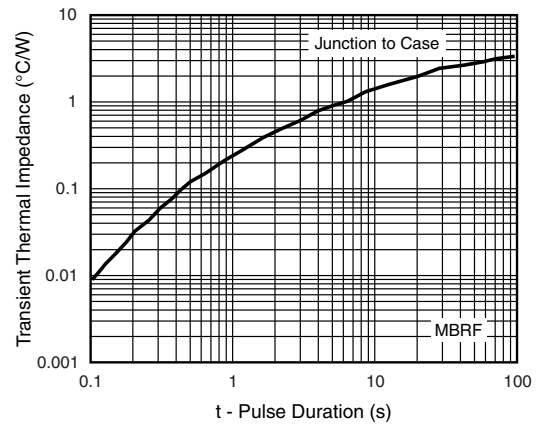


Figure 7. Typical Transient Thermal Impedance

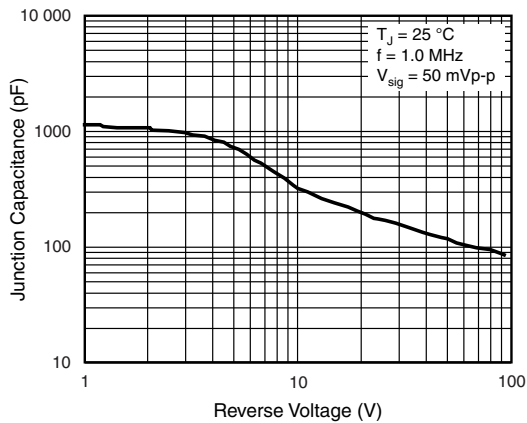


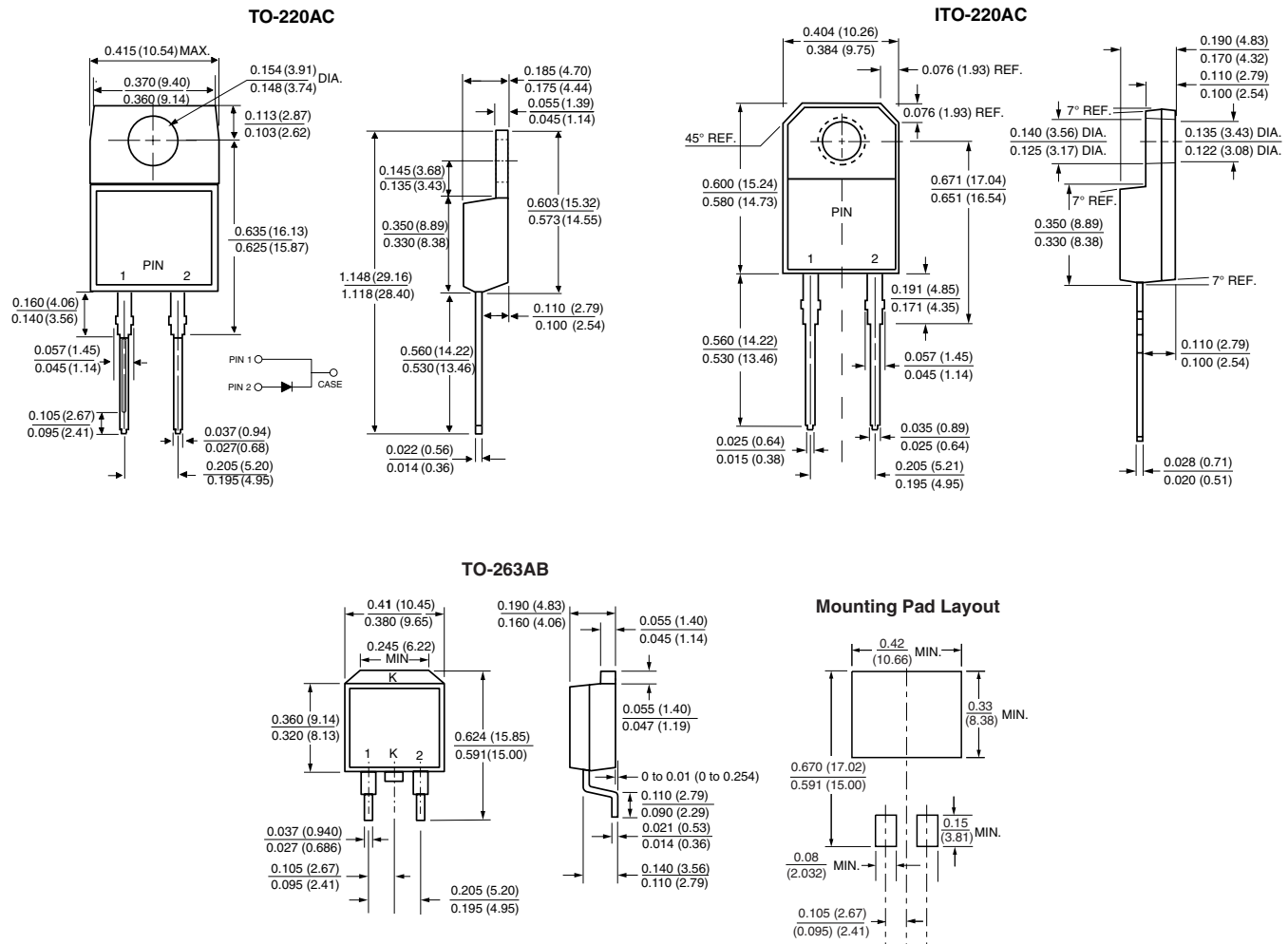
Figure 5. Typical Junction Capacitance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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